

# MgB<sub>2</sub> Narrow Film Fabrication Using Pulsed Beam Deposition: A Short Communication

Mehaboobi Khan\*

Department of Physics, Louisiana State University, Baton Rouge, LA, USA

## Introduction

Magnesium diboride (MgB<sub>2</sub>) with the superconducting change temperature T<sub>c</sub>=39 K has an extraordinary potential for superconducting electronic applications cooled with fluid hydrogen (LH2) option in contrast to fluid helium-based cryogenic frameworks. Notwithstanding its somewhat high T<sub>c</sub>, MgB<sub>2</sub> shows a great deal of captivating properties, for example, a straightforward layer structure, lower anisotropy, and longer intelligence length, when contrasted and cuprate high-T<sub>c</sub> superconductors [1]. Also, the straightforwardness of the grain limits to current stream and the wealth of Mg and B offer the chance of utilizing MgB<sub>2</sub> for gadget applications.

## Description

Epitaxial MgB<sub>2</sub> films empower the creation of the superconducting electronic applications, for example, superconducting indicators (progress edge sensors (TES) and superconducting burrow intersections (STJ)), advanced circuits, and diodes [2,3]. Enormous headway has been made upon the fruitful utilization of an assortment of testimony methods, like sub-atomic shaft epitaxy (MBE), beat laser statement (PLD), electron bar dissipation (EBE), crossover physical-compound fume statement (HPCVD), receptive vanishing and magnetron faltering. Two of the main necessities for the manufacture of MgB<sub>2</sub> dainty movies are: (i) to give an adequately high Mg fume tension for stage soundness of MgB<sub>2</sub> and (ii) to wipe out the leftover oxygen during the slender film combination in view of the great responsiveness of Mg to oxidation. MgB<sub>2</sub> films have been created through the PLD strategy not long after the disclosure of superconductivity in this material [4].

KrF (λ=248 nm) excimer lasers are widely used for PLD due to their high photon energy and light intensity. However, these excimer lasers are costly and use poisonous halogen gases for excitation. A feasible way to overcome these drawbacks would be to use a Nd:YAG (neodymium-doped yttrium aluminium garnet; Nd:Y3Al5O12) solid state laser instead. The Nd:YAG laser is highly stable and safe compared with excimer lasers, which use toxic gas. The fundamental wavelength of the Nd:YAG laser is 1064 nm. However, ultraviolet light can be generated by changing harmonic crystals to the fourth harmonic of the Nd:YAG's fundamental wavelength (λ=266 nm). At this wavelength, the Nd:YAG laser has a photon energy comparable to the KrF excimer laser's fundamental mode (λ=248 nm) [5]. The Nd:YAG laser also has additional advantages over the excimer lasers associated with their low installation, maintenance costs, and compact footprint. Hence, the Nd:YAG laser could be a potential alternative to excimer lasers for the PLD system. However, there are only few reports on MgB<sub>2</sub> films fabricated by the Nd:YAG

laser. In this paper, we report the fabrication of superconducting MgB<sub>2</sub> thin films via an in situ PLD process using the fourth harmonic of the Nd:YAG laser. The influence of the Mg-B target composition on T<sub>c</sub> of the films is investigated. We also present the structural and superconducting properties of the obtained MgB<sub>2</sub> films.

The common creation interaction of MgB<sub>2</sub> flimsy movies comprises of a forerunner, become by the PLD technique at room temperature, and a postannealing cycle. The postannealing processes are delegated: (i) *ex situ*, which is acted in a metal cylinder under a Mg climate after the antecedent testimony in a chamber and (ii) *in situ*, which is acted in a similar chamber as the statement chamber for the forerunner films under vacuum, Ar or Ar/4%H<sub>2</sub> environment. The MgB<sub>2</sub> films created with a forerunner, become by the PLD strategy, and *in situ* postannealed (*in situ* PLD process) showed a zero-field T<sub>c</sub> zero of 29 K and a self-field J<sub>c</sub> of 2 × 10<sup>5</sup> A cm<sup>-2</sup> at 5 K.

## Conclusion

J<sub>c</sub> (T) of MgB<sub>2</sub> film #2 is estimated to be 0.9 10<sup>6</sup> A cm<sup>2</sup> at 20 K based on attractive hysteresis estimates. According to the vehicle assessment in the rakish dependency on J<sub>c</sub> in the attractive field, MgB<sub>2</sub> film #2 has greater J<sub>c</sub> at=90° (H/film surface), which could reflect the granular grain structure. By calibrating the creation interaction, we intend to get greater superconducting characteristics. Our findings show that the *in situ* planning methodology with Nd:YAG laser cycles are advantageous for the production of superconducting devices over the excimer laser process.

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Not applicable.

## Conflict of Interest

There is no conflict of interest by author.

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\*Address for Correspondence: Mehaboobi Khan, Department of Physics, Louisiana State University, Baton Rouge, LA, USA, E-mail: mehaboobi.k@yahoo.edu

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